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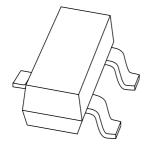
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

# DISCRETE SEMICONDUCTORS

# DATA SHEET



# **BFS20**NPN medium frequency transistor

Product data sheet Supersedes data of 2004 Jan 5 2004 Feb 05



NXP Semiconductors Product data sheet

# NPN medium frequency transistor

**BFS20** 

#### **FEATURES**

- I<sub>C(max)</sub> = 25 mA
- V<sub>CEO(max)</sub> = 20 V
- Very low feedback capacitance (typ. 350 fF).

#### **APPLICATIONS**

• IF and VHF thick and thin-film circuit applications.

#### **DESCRIPTION**

NPN medium frequency transistor in a SOT23 plastic package.

#### **MARKING**

TYPE NUMBER	MARKING CODE(1)
BFS20	G1*

#### Note

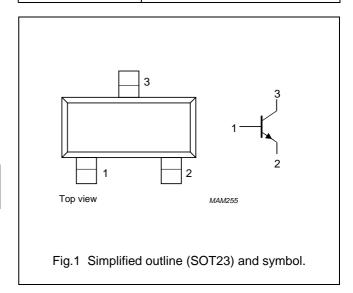
1. \* = p: Made in Hong Kong.

\* = t : Made in Malaysia.

\* = W : Made in China.

#### **PINNING**

PIN	DESCRIPTION
1	base
2	emitter
3	collector



#### **ORDERING INFORMATION**

TYPE	PACKAGE					
NUMBER	NAME	ME DESCRIPTION VERSION				
BFS20	_	plastic surface mounted package; 3 leads	SOT23			

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	_	30	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	20	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	4	V
I <sub>C</sub>	collector current (DC)		_	25	mA
I <sub>CM</sub>	peak collector current		_	25	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

NXP Semiconductors Product data sheet

# NPN medium frequency transistor

BFS20

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V	_	_	100	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V; T <sub>j</sub> = 100 °C	_	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 4 V	_	_	100	nA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 7 mA; V <sub>CE</sub> = 10 V	40	85	_	
$V_{BE}$	base-emitter voltage	I <sub>C</sub> = 7 mA; V <sub>CE</sub> = 10 V	_	740	900	mV
C <sub>c</sub>	collector capacitance	I <sub>E</sub> = I <sub>e</sub> = 0; V <sub>CB</sub> = 10 V; f = 1 MHz	_	1	_	pF
C <sub>re</sub>	feedback capacitance	I <sub>C</sub> = 0; V <sub>CB</sub> = 10 V; f = 1 MHz	_	350	_	fF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 5 mA; V <sub>CE</sub> = 10 V; f = 100 MHz	275	450	_	MHz

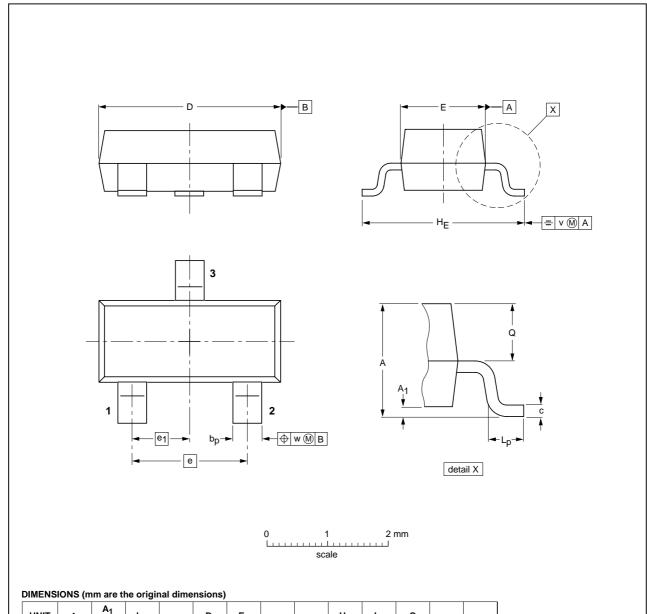
# NPN medium frequency transistor

BFS20

#### **PACKAGE OUTLINE**

#### Plastic surface-mounted package; 3 leads

SOT23



UNIT	Α	max.	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	V	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE		REFERENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>-04-11-04</del> 06-03-16

NXP Semiconductors Product data sheet

### NPN medium frequency transistor

BFS20

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published
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## **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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